

1 **Supporting Information**

2 **An *in situ* growth route towards anti-perovskite Ni₃InN nanoparticles embedded within**
3 **amorphous silicon nitride**

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20 **Keywords**

21 **Anti-perovskite, Ni₃InN, amorphous silicon nitride, polymer-derived ceramics (PDCs)**

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27 1. Synthesis of Ni_{0.1}In_{0.1}-PH sample

28 The handling of the chemicals and reagents was performed under an inert atmosphere of
29 pure argon (Ar) using standard Schlenk techniques and vacuum/Ar lines. Commercially
30 available perhydropolysilazane (PHPS, NN120-20, 20 wt% in dibutyl ether solution) was
31 provided by Sanwa Kagaku, Corp., Shizuoka, Japan. The dibutyl ether was substituted by
32 super-anhydrous toluene (99.5 % purity, Wako Pure Chemical Industries, Ltd., Osaka, Japan)
33 to be 20 wt% for the PHPS contents.

34 In a typical experiment for Ni_{0.1}In_{0.1}-PH sample, a 100 mL two-neck round-bottom flask
35 equipped with a magnetic stirrer was charged with the solvent-substituted PHPS (10 mL, 44
36 mmol, 20 wt% in toluene) and toluene (30 mL), then NiCl₂ (0.59 g, 4.4 mmol, Ni/Si = 0.1) and
37 InCl₃ (0.98 g, 4.4 mmol, In/Si = 0.1) were added to the solution at room temperature. The
38 reaction mixture was vigorously stirred at R.T. for 30 min and subsequently refluxed at 110 °C
39 for 15 h under flowing Ar with maintaining vigorous stirring. After the reaction mixture was
40 cooled to room temperature, the toluene solvent was removed under vacuum at 60 °C to give
41 a Ni_{0.1}In_{0.1}-PH sample.

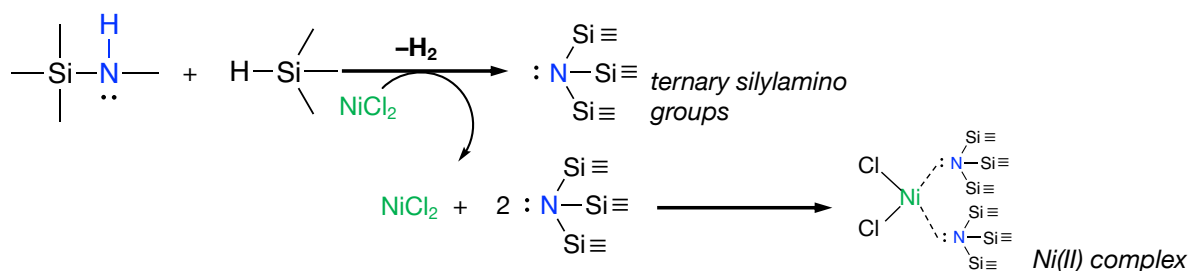
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43 2. Supporting data

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45 **Scheme S1** Dehydrogenation reaction of Si-H/N-H in PSZ catalyzed by NiCl₂ and possible
46 Ni(II) coordination structures such as 4-coordinate Ni(II) complex.

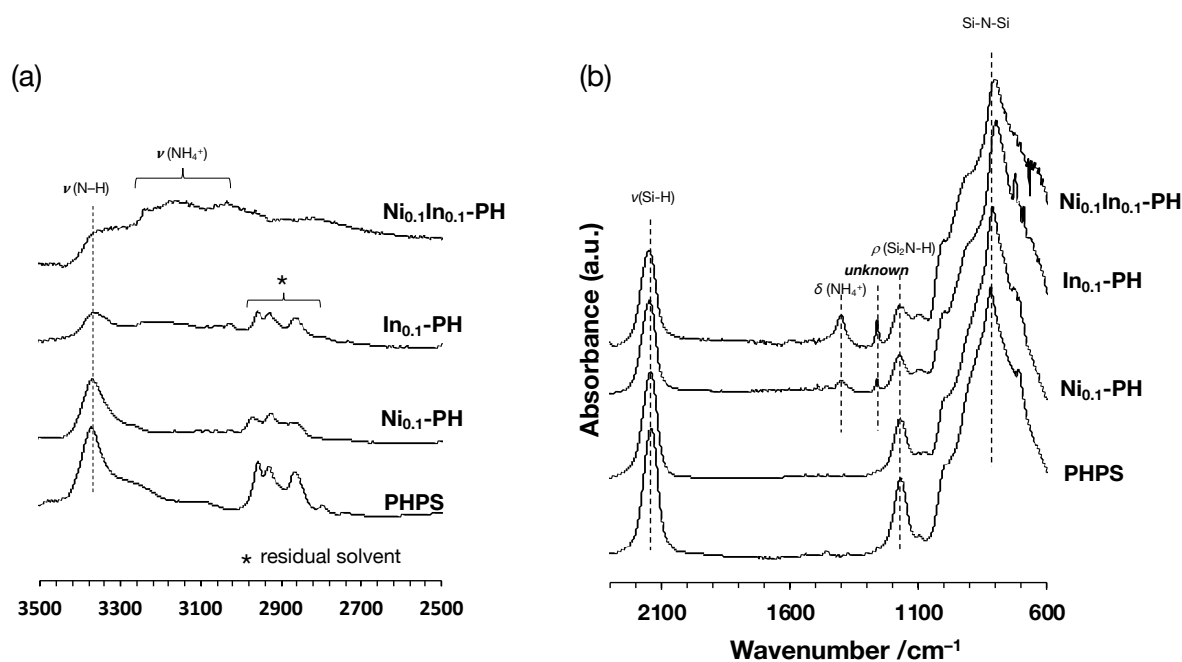
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59 **Table S1** The selected absorption bands position, band shift and relative intensity to $\nu\text{Si-N-Si}$
 60 ($I_{\text{band}}/I_{\text{Si-N-Si}}$) in the ATR-FTIR spectra for $\text{Ni}_x\text{In}_{0.1}\text{-DRZ}$ samples.

Band	Sample	Wavenumber /cm ⁻¹	Band shift /cm ⁻¹	Relative intensity ($I_{\text{band}} / I_{\text{Si-N-Si}}$)
$\nu(\text{Si-N-Si})$	Durazane [®] 1800	881.3	-	1
	In _{0.1} -DRZ	876.5	-4.82	1
	Ni _{0.05} In _{0.1} -DRZ	880.4	-0.96	1
	Ni _{0.1} In _{0.1} -DRZ	881.3	0	1
$\nu(\text{N-H})$	Durazane [®] 1800	3378.7	-	0.237
	In _{0.1} -DRZ	3400.9	22.2	0.157
	Ni _{0.05} In _{0.1} -DRZ	3398.0	19.3	0.092
	Ni _{0.1} In _{0.1} -DRZ	3398.9	20.2	0.091
$\rho(\text{Si}_2\text{N-H})$	Durazane [®] 1800	1160.9	-	0.508
	In _{0.1} -DRZ	1133.0	-27.9	0.244
	Ni _{0.05} In _{0.1} -DRZ	1140.7	-20.2	0.158
	Ni _{0.1} In _{0.1} -DRZ	1133.0	-27.9	0.133
$\nu(\text{Si-H})$	Durazane [®] 1800	2121.3	-	0.241
	In _{0.1} -DRZ	2123.2	1.9	0.163
	Ni _{0.05} In _{0.1} -DRZ	2128.1	6.8	0.102
	Ni _{0.1} In _{0.1} -DRZ	2130.0	8.7	0.068
$\delta(\text{Si-CH}_3)$	Durazane [®] 1800	1253.5	-	0.278
	In _{0.1} -DRZ	1254.5	1	0.329
	Ni _{0.05} In _{0.1} -DRZ	1256.4	2.9	0.321
	Ni _{0.1} In _{0.1} -DRZ	1259.3	5.8	0.354
$\delta(\text{C-H, Vinyl})$	Durazane [®] 1800	1403.9	-	0.058
	In _{0.1} -DRZ	1403.0	-0.9	0.109
	Ni _{0.05} In _{0.1} -DRZ	1403.0	-0.9	0.087
	Ni _{0.1} In _{0.1} -DRZ	1403.0	-0.9	0.120

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78 **Fig. S1** ATR-FTIR spectra of as-synthesized Ni_xIn_y-PH samples in the range of (a) 3500–2500
 79 cm⁻¹ and (b) 2300–600 cm⁻¹.

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81 [FTIR analysis]

82 As reference spectra, as-received PHPS was recorded. FTIR (ATR /cm⁻¹): 3373 (νN-H),
 83 2143 (νSi-H), 1172 (ρSi₂N-H) and 822 (νSi-N-Si) [1-5]. The νSi-N-Si stretching bands for
 84 NiCl₂ and InCl₃-*co*-modified PHPS samples indicated all lower wavenumber (WN) values than
 85 those for as-received PHPS sample. The absorption band shift of the νSi-N-Si on Ni_{0.1}-PH,
 86 In_{0.1}-PH, and Ni_{0.1}In_{0.1}-PH samples were measured to be -7.7, -22.2, and -20.3 cm⁻¹,
 87 respectively. It was found that the extent of band shift is greater in In_{0.1}-PH and Ni_{0.1}In_{0.1}-PH
 88 samples compared to the Ni_{0.1}-PH sample. In addition, the chemical modification of PHPS
 89 with NiCl₂ and InCl₃ resulted in a reduction of the relative intensity on both ρSi₂N-H and νSi-
 90 H bands. The extent of decreased intensities of both ρSi₂N-H and νSi-H was greater for In_{0.1}-
 91 PH and Ni_{0.1}In_{0.1}-PH samples compared to Ni_{0.1}-PH sample. The νSi-H stretching band varies
 92 toward higher WN values in the range 2142–2152 cm⁻¹. The vibrational frequency of the νSi-
 93 H increases either through the electronegativity (*X*) of the substituting group increases [6] or
 94 through the increase of nitrogen concentration within the precursors [7], *i.e.*, the substitution
 95 of H atoms (*X* = 2.2 by Pauling scale) with N atoms (*X* = 3.0 by Pauling scale) on Si atoms
 96 back bonded to Si-H bonds. The substitution leads to the νSi-H stretching mode toward higher

97 frequency due to the induction effect. This result is consistent with the formation of the ternary
98 silylamino group during reflux at 110 °C. Additionally, new absorption bands appeared on
99 **In_{0.1}-PH** and **Ni_{0.1}In_{0.1}-PH** samples (**Fig. S1a**) at 3240, 3150, and 1404 cm⁻¹, which are
100 assigned to ammonium salt, most probably ammonium chloride (NH₄Cl) [8].

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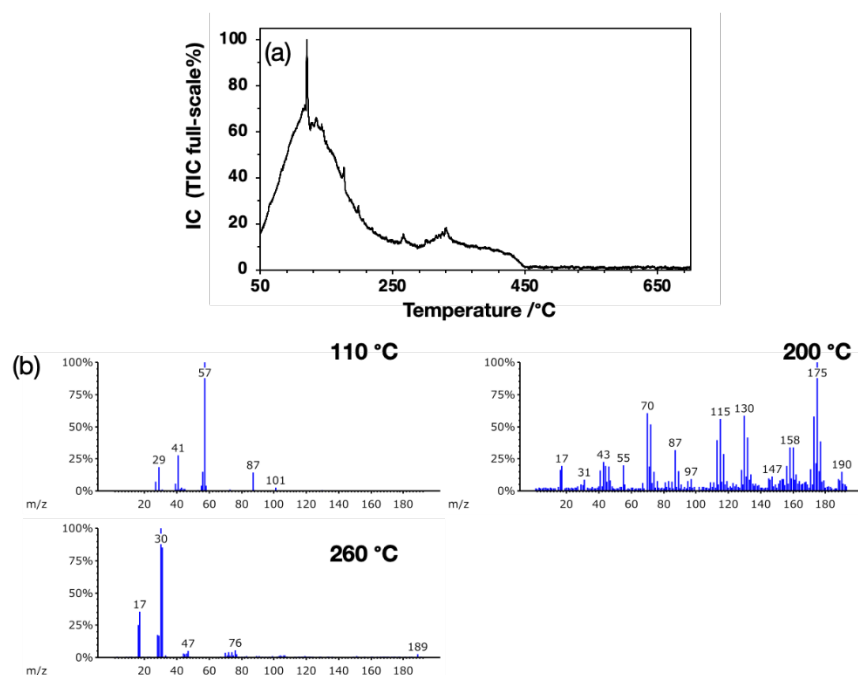
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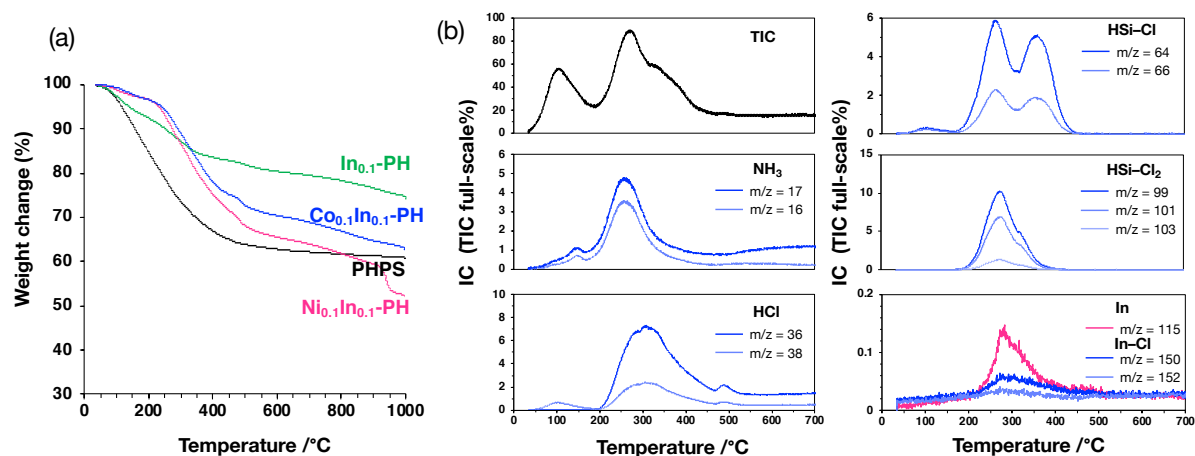
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132 **Fig. S2** TG-MS analysis of PHPS: (a) The total ion current (TIC) chromatogram and (b) mass
 133 fragments at selected temperatures.

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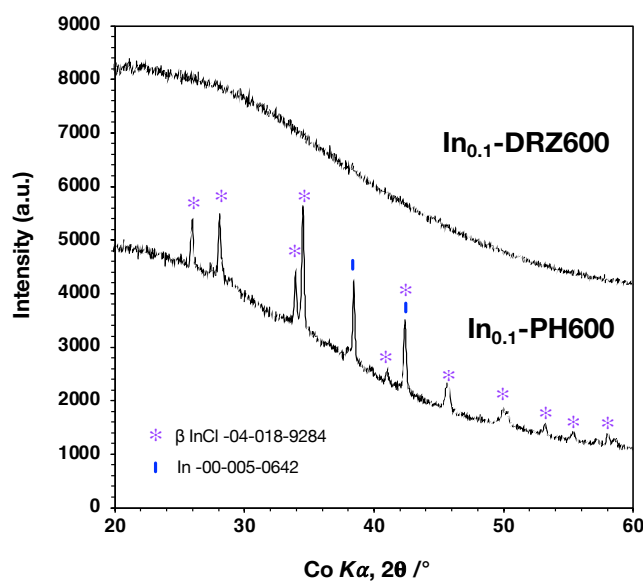


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138 **Fig. S3** (a) TG-curves of starting PHPS and as-synthesized $\text{M}_x\text{In}_{0.1}\text{-PH}$ samples (M = Ni and
 139 Co, x = 0 or 0.1) to 1000 °C under He and (b) the total ion current (TIC) chromatogram and
 140 selected mass fragments measured for $\text{Ni}_{0.1}\text{In}_{0.1}\text{-PH}$ sample during TG-MS analysis.

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143 **Fig. S4** XRD patterns of (a) **In_{0.1}-PH600** and (b) **In_{0.1}-DRZ600** samples

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146 **[TG-MS analysis]**

147 The TG-curve of as-received PHPS (**Fig. S3a**) displays a weight loss at 50–550 °C,
 148 resulting in a final ceramic yield of 60.9 %. According to the MS analyses of as-received PHPS
 149 (**Fig. S3b**), these weight losses are due to the volatilization of residual solvents such as dibutyl
 150 ether (mass spectra measured at 110 °C, $m/z = 57, 41, 29$), low molecular weight organosilicon
 151 compounds such as $\equiv\text{Si}-\text{NH}-$ (mass spectra measured at 200 °C, $m/z = 43$) and NH_3 ($m/z =$
 152 17), which are associated with cross-linking reactions of the precursor through trans-amination,
 153 and bond redistribution reactions.

154 The **Ni_{0.1}In_{0.1}-PH** and **Co_{0.1}In_{0.1}-PH** samples showed similar behavior of weight loss (**Fig.**
 155 **S3a**). The weight loss at 50-300 °C was significantly suppressed compared to the as-received
 156 PHPS. As discussed in the FTIR results (**Fig. S1**), the catalytic cross-linking reaction of the
 157 PSZ network during polymer synthesis through the dehydrocoupling reaction of Si-H/N-H
 158 catalyzed by MCl_2 helps to suppress the weight loss in this temperature range. In contrast to
 159 **M_{0.1}In_{0.1}-PH** samples, the **In_{0.1}-PH** sample showed less pronounced weight loss suppression
 160 in this temperature range, possibly due to either the quantitative dependence or the participation
 161 of a different reaction—*i.e.*, acid-base reaction—for **In_{0.1}-PH** sample.

162 The weight loss from 330 °C to 500 °C is greater in **Ni_{0.1}In_{0.1}-PH** and **Co_{0.1}In_{0.1}-PH**
 163 samples, indicating the volatilization of InCl_3 which usually starts at 330 °C under an inert
 164 atmosphere [1]. There was no significant difference in the weight loss of **Ni_{0.1}In_{0.1}-PH** and
 165 **Co_{0.1}In_{0.1}-PH** samples, with the difference being within about 5% at 550 °C; however, the Co

166 species showed a smaller weight loss. In contrast, the **In_{0.1}-PH** sample showed a featureless
 167 slope in this temperature range, suggesting that the in situ formation of In–N bond via acid-
 168 base reaction during synthesis reduced the amount of unreacted InCl₃ which evaporated at
 169 around 330 °C. Weight loss from 550 °C is not observed in as-received PHPS but is observed
 170 in **In_{0.1}-PH**, **Ni_{0.1}In_{0.1}-PH** and **Co_{0.1}In_{0.1}-PH** samples suggesting that the decomposition of the
 171 in situ formed In-N bonds occurred over 550 °C under an inert atmosphere [2].

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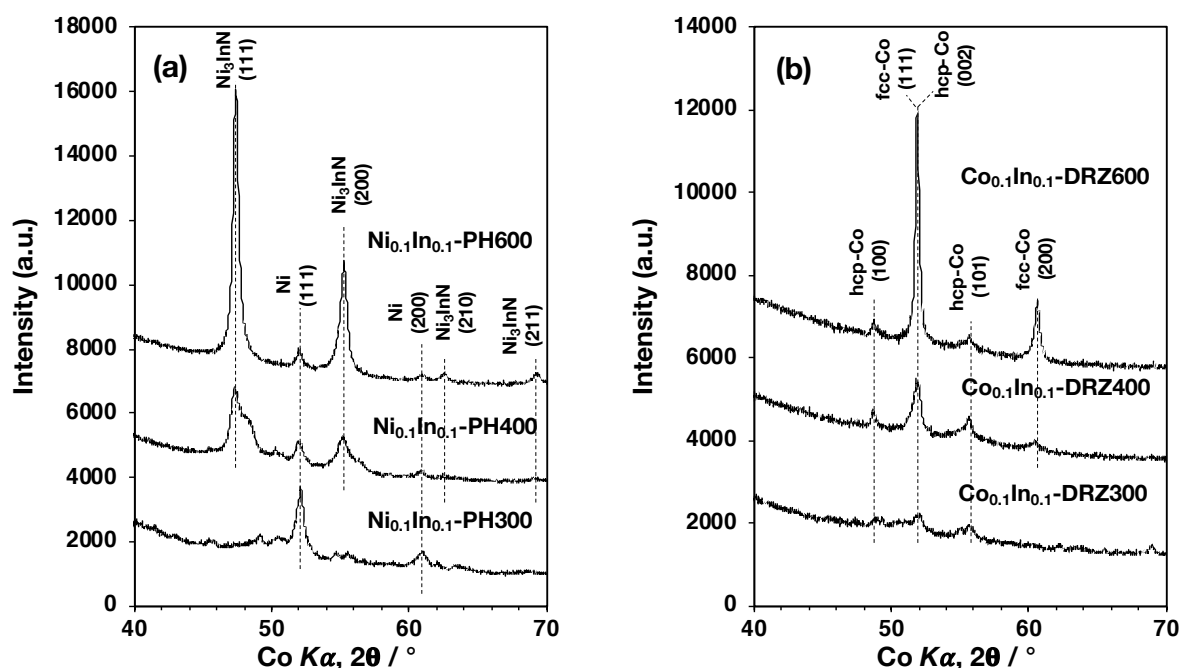
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182 **Fig. S5** XRD patterns of (a) **Ni_{0.1}In_{0.1}-PHT** and (b) **Co_{0.1}In_{0.1}-DRZT** samples, *T* is pyrolysis
 183 temperatures (300, 400, and 600 °C).

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190 **Table S2** Chemical composition of as-pyrolyzed $\text{Ni}_{0.1}\text{In}_{0.1}\text{-PHT}$ samples ($T = 300, 400,$ and
 191 600)

Name	Composition (wt%)							Atomic ratio normalized on Si
	Si	C	N	O	Ni	In	Cl	
$\text{Ni}_{0.1}\text{In}_{0.1}\text{-PH300}$	44.26	0.51	25.52	3.03	11.23	9.20	6.26	$\text{Si}_1\text{N}_{1.16}\text{O}_{0.12}\text{Ni}_{0.12}\text{In}_{0.05}\text{Cl}_{0.11}$
$\text{Ni}_{0.1}\text{In}_{0.1}\text{-PH400}$	45.44	0.43	27.96	2.76	10.79	7.26	5.36	$\text{Si}_1\text{N}_{1.23}\text{O}_{0.11}\text{Ni}_{0.11}\text{In}_{0.04}\text{Cl}_{0.09}$
$\text{Ni}_{0.1}\text{In}_{0.1}\text{-PH600}$	40.55	0.38	31.80	4.21	12.41	6.98	3.67	$\text{Si}_1\text{N}_{1.57}\text{O}_{0.18}\text{Ni}_{0.15}\text{In}_{0.04}\text{Cl}_{0.07}$

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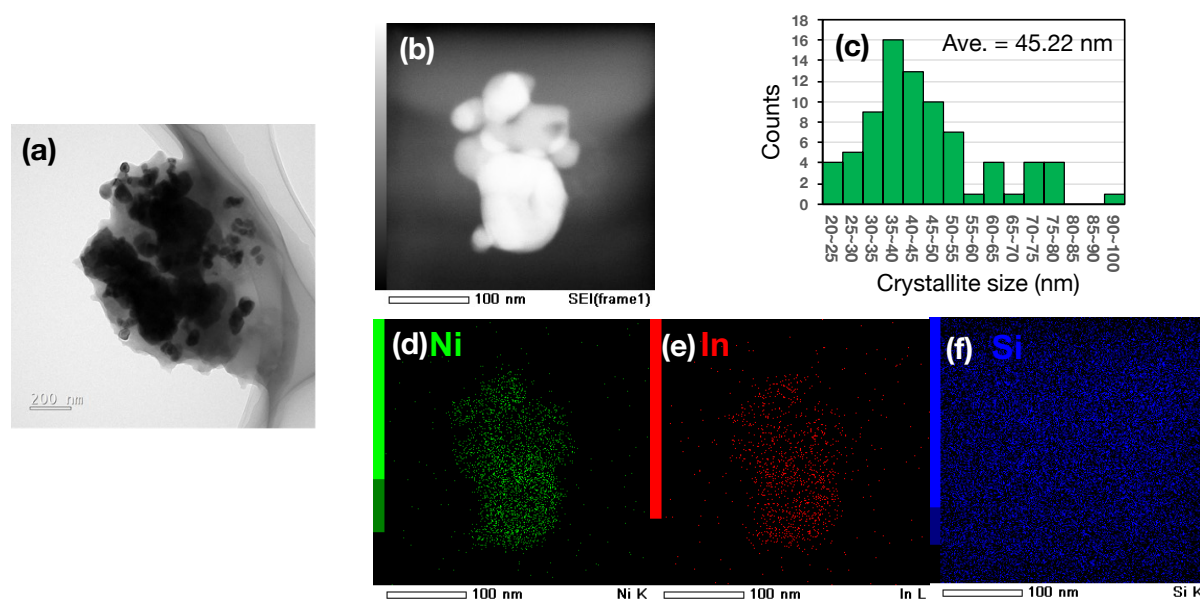
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194 **Table S3** Chemical composition of as-pyrolyzed $\text{Co}_{0.1}\text{In}_{0.1}\text{-DRZT}$ samples ($T = 300, 400,$ and
 195 600)

Name	Composition (wt%)							Atomic ratio normalized on Si
	Si	C	N	O	Co	In	Cl	
$\text{Co}_{0.1}\text{In}_{0.1}\text{-DRZ300}$	37.65	4.94	21.88	3.35	9.43	13.72	9.04	$\text{Si}_1\text{Co}_{0.31}\text{N}_{1.17}\text{O}_{0.16}\text{Co}_{0.12}\text{In}_{0.09}\text{Cl}_{0.19}$
$\text{Co}_{0.1}\text{In}_{0.1}\text{-DRZ400}$	33.43	0.68	29.25	7.88	9.44	10.29	9.03	$\text{Si}_1\text{Co}_{0.05}\text{N}_{1.75}\text{O}_{0.41}\text{Co}_{0.13}\text{In}_{0.08}\text{Cl}_{0.21}$
$\text{Co}_{0.1}\text{In}_{0.1}\text{-DRZ600}$	43.76	0.39	31.79	4.25	16.78	0.13	2.89	$\text{Si}_1\text{Co}_{0.02}\text{N}_{1.46}\text{O}_{0.17}\text{Co}_{0.18}\text{In}_{0.00}\text{Cl}_{0.05}$

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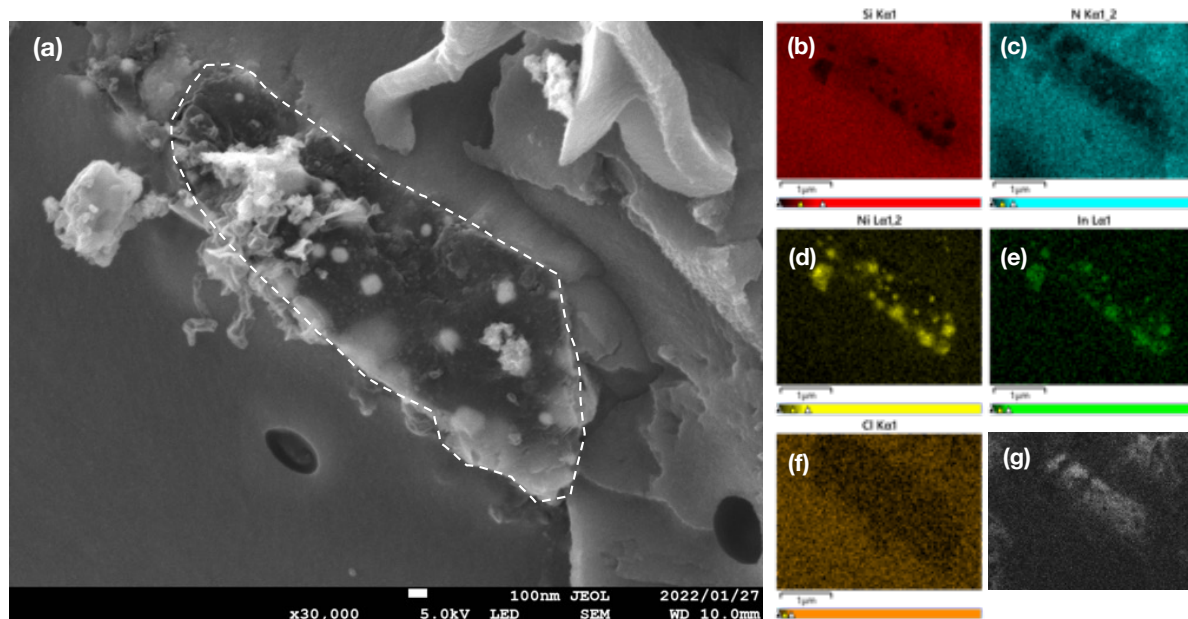


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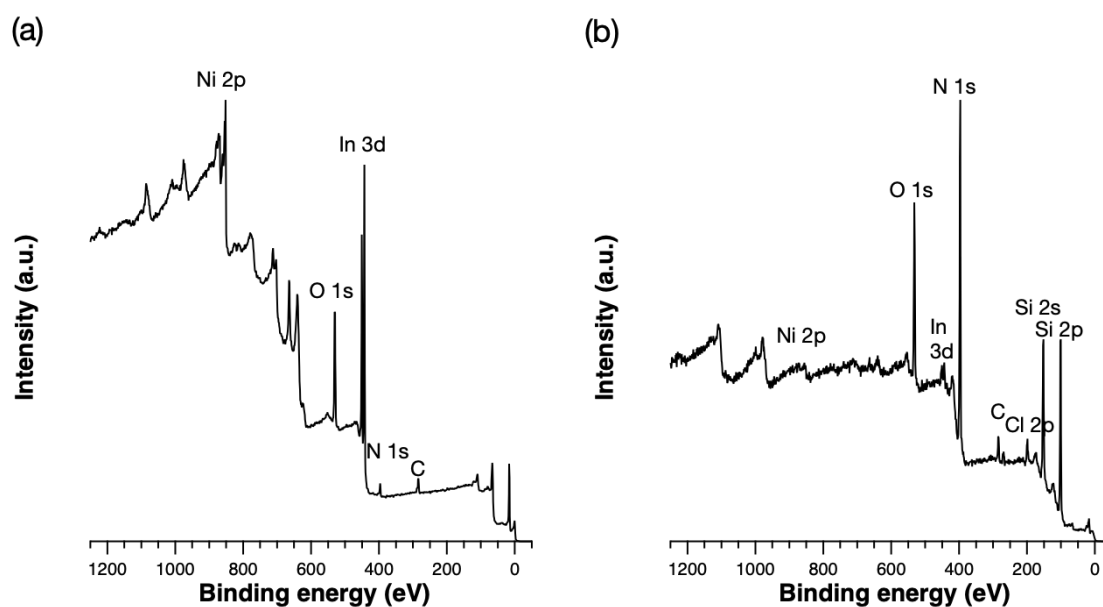
200 **Fig. S6** (a) BF-TEM image and (b) HAADF-STEM image of the $\text{Ni}_{0.05}\text{In}_{0.1}\text{-DRZ600}$ sample.
 201 (c) the Ni_3InN crystallite size distribution, and the result of STEM-EDS mapping of (d) Ni,
 202 In and (f) Si.

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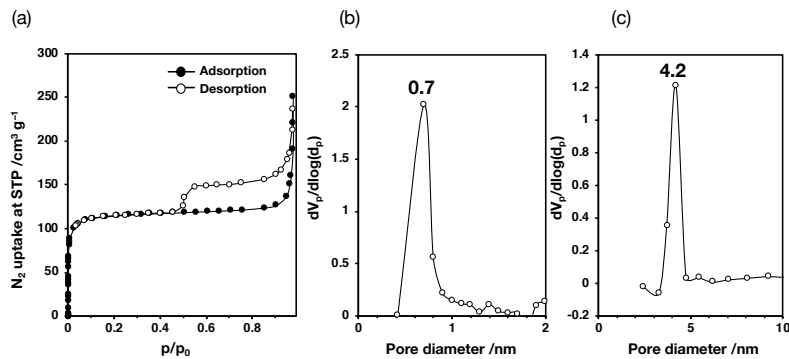
Fig. S7 SEM-EDS and SEM-CL image analysis for the $\text{Ni}_{0.1}\text{In}_{0.1}\text{-PH600}$ sample: (a) SEM image, and the results of EDS mapping of (b) Si, (c) N, (d) Ni, (e) In, and (f) Cl. (g) the SEM-CL image of the selected area around the nanoparticles. The white dashed line represents the monolithic region of a-SiN matrix.



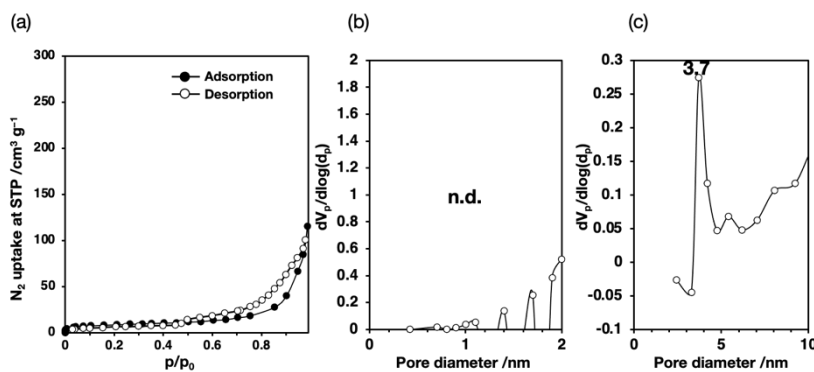
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Fig. S8 XPS survey scan spectra for (a) bulk Ni_3InN and (b) $\text{Ni}_3\text{InN/SiN}$ nanocomposite ($\text{Ni}_{0.1}\text{In}_{0.1}\text{-PH600}$ sample)

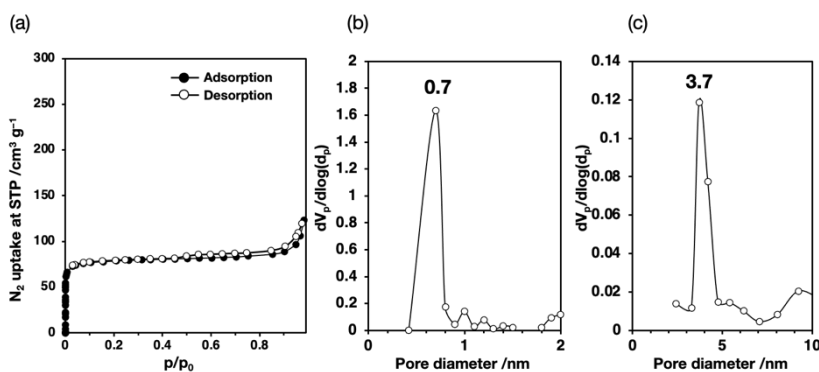
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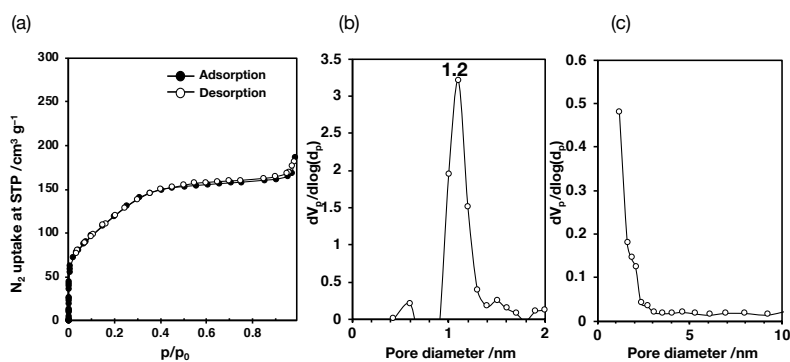
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219 **Fig. S9** (a) N₂ adsorption and desorption isotherms at -196 °C for Ni_{0.05}In_{0.1}-DRZ600 sample,
220 and the resulting pore size distribution curve characterized by the (b) MP plot and (c) BJH plot.
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222 **Fig. S10** (a) N₂ adsorption and desorption isotherms at -196 °C for Ni_{0.1}In_{0.1}-PH600 sample,
223 and the resulting pore size distribution curve characterized by the (b) MP plot and (c) BJH plot.
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225 **Fig. S11** (a) N₂ adsorption and desorption isotherms at -196 °C for Ni_{0.1}In_{0.1}-DRZ600 sample,
226 and the resulting pore size distribution curve characterized by the (b) MP and (c) BJH plot.



228 **Fig. S12** (a) N₂ adsorption and desorption isotherms at -196 °C for **In_{0.1}-DRZ600**, and the
 229 resulting pore size distribution curve characterized by the (b) MP and (c) BJH plot.

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232 **Table S4** The Brunauer–Emmett–Teller (BET) surface areas and pore volumes of pyrolyzed
 233 samples.

Samples	S_{BET} /m² g⁻¹	V_{BET, total} /cm³ g⁻¹	V_{micro} /cm³ g⁻¹	V_{meso} /cm³ g⁻¹
Ni_{0.1}In_{0.1}-PH600	32	0.18	n.d.	0.17
Ni_{0.05}In_{0.1}-DRZ600	460	0.39	0.19	0.18
Ni_{0.1}In_{0.1}-DRZ600	315	0.19	0.13	0.08
In_{0.1}-DRZ600	441	0.29	0.24	n.d.

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